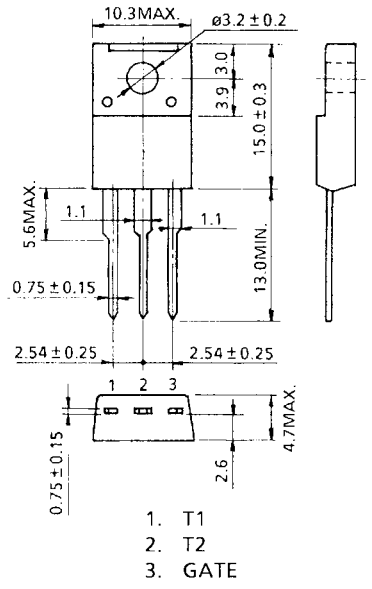
TOSHIBA BI−DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

SM2GZ47,SM2GZ47A,SM2JZ47,SM2JZ47A

AC POWER CONTROL APPLICATIONS

- $I_{T\ (RMS)}$ = 1A (Ta = 65°C without radiator)
- Gate Trigger Current : I_{GT} = 5mA Max. (TYPE "A")
- Repetitive Peak Off−State Voltage : V_{DRM} = 400V, 600V
- R.M.S On−State Current : $I_{T\ (RMS)}$ = 2A (Tc = 110°C)
- Isolation Voltage : V_{ISOL} = 1500V (AC, t = 60s)

Unit: mm



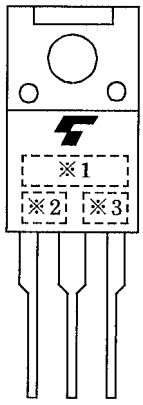
JEDEC	—
JEITA	—
TOSHIBA	13−10H1A

Weight: 1.7g (Typ.)

MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Off−State Voltage and Repetitive Peak Reverse Voltage	SM2GZ47 SM2GZ47A	V_{DRM}	400	V
	SM2JZ47 SM2JZ47A		600	
R.M.S On−State Current (Full Sine Waveform)	Tc = 110°C	$I_{T\ (RMS)}$	2	A
	Ta = 65°C		1	
Peak One Cycle Surge On−State Current (Non−Repetitive)		I_{TSM}	8 (50Hz)	A
			8.8 (60Hz)	
I^2t Limit Value		I^2t	0.32	A^2s
Peak Gate Power Dissipation		P_{GM}	3	W
Average Gate Power Dissipation		$P_{G\ (AV)}$	0.3	W
Peak Gate Voltage		V_{FGM}	10	V
Peak Gate Current		I_{GM}	1.6	A
Junction Temperature		T_j	−40~125	°C
Storage Temperature Range		T_{stg}	−40~125	°C
Isolation Voltage (AC, t = 1min.)		V_{ISOL}	1500	V

MARKING

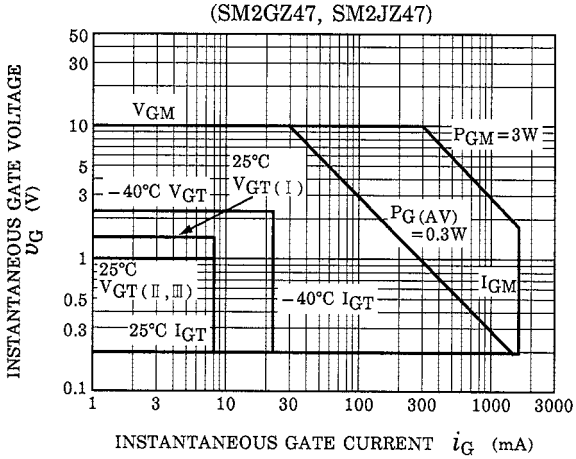


NUMBER	SYMBOL		MARK
*1	TYPE	SM2GZ47, SM2GZ47A	M2GZ47
		SM2JZ47, SM2JZ47A	M2JZ47
*2		SM2GZ47A, SM2JZ47A	A
*3	Lot Number □ □ Month (Starting from Alphabet A) Year (Last Decimal Digit of the Current Year)		Example 8A : January 1998 8B : February 1998 8L : December 1998

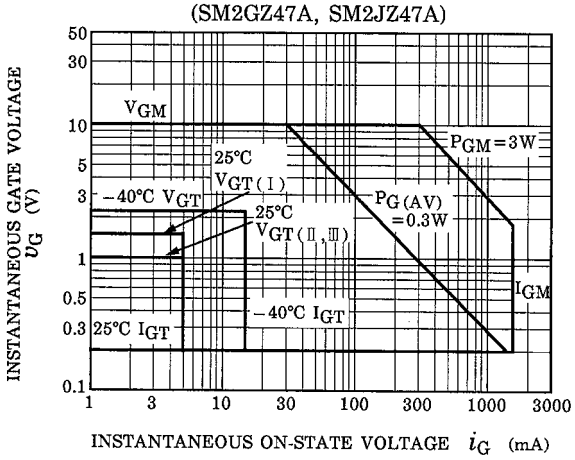
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC			SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off−State Current			I_{DRM}	V_{DRM} = Rated		—	—	20	μA
Gate Trigger Voltage		I	V_{GT}	V_D = 12V R_L = 20Ω	T2 (+) , Gate (+)	—	—	1.5	V
		II			T2 (+) , Gate (−)	—	—	1	
		III			T2 (−) , Gate (−)	—	—	1	
		IV			T2 (−) , Gate (+)	—	—	—	
Gate Trigger Current	SM2GZ47 SM2JZ47	I	I_{GT}	V_D = 12V R_L = 20Ω	T2 (+) , Gate (+)	—	—	8	mA
		II			T2 (+) , Gate (−)	—	—	8	
		III			T2 (−) , Gate (−)	—	—	8	
		IV			T2 (−) , Gate (+)	—	—	—	
	SM2GZ47A SM2JZ47A	I			T2 (+) , Gate (+)	—	—	5	
		II			T2 (+) , Gate (−)	—	—	5	
		III			T2 (−) , Gate (−)	—	—	5	
		IV			T2 (−) , Gate (+)	—	—	—	
Peak On−State Voltage			V_{TM}	I_{TM} = 3A		—	—	1.7	V
Gate Non−Trigger Voltage			V_{GD}	V_D = Rated, Tc = 125°C		0.2	—	—	V
Holding Current			I_H	R_L = 100Ω		—	—	10	mA
Thermal Resistance			$R_{th\ (j-a)}$	Junction to Ambient, AC		—	—	55	°C / W

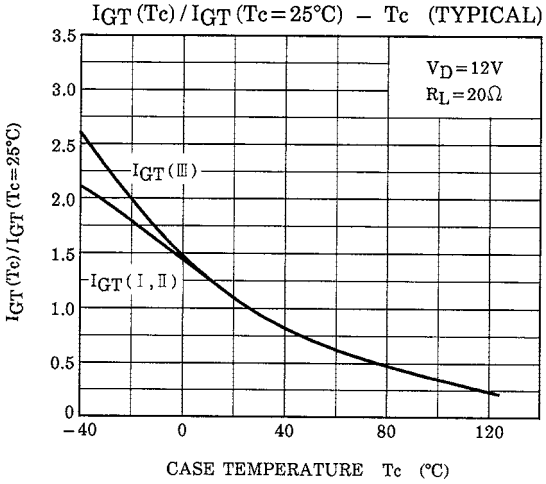
GATE TRIGGER CHARACTERISTIC
(SM2GZ47, SM2JZ47)



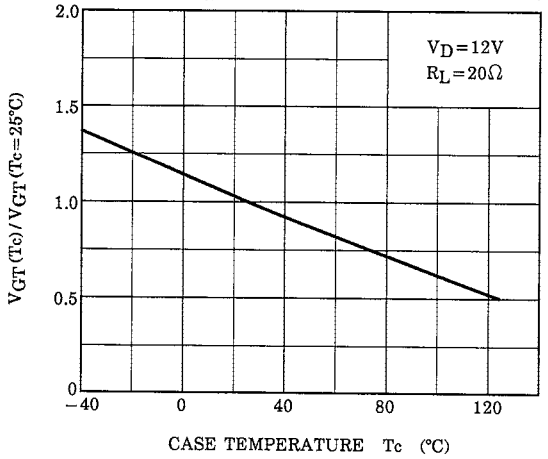
GATE TRIGGER CHARACTERISTIC
(SM2GZ47A, SM2JZ47A)



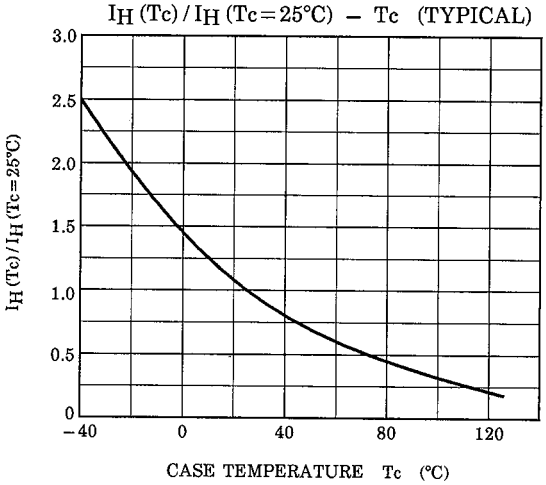
I_{GT} (Tc) / I_{GT} (Tc = 25°C) – Tc (TYPICAL)



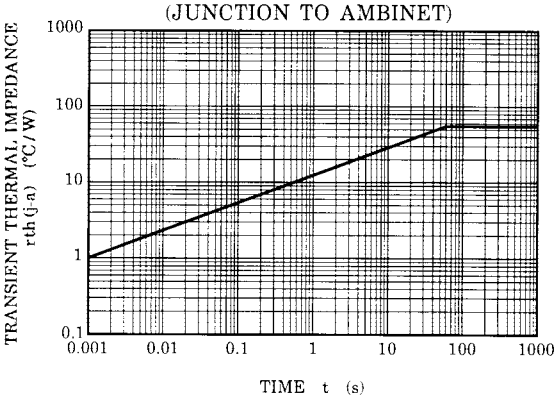
V_{GT} (Tc) / V_{GT} (Tc = 25°C) – Tc (TYPICAL)

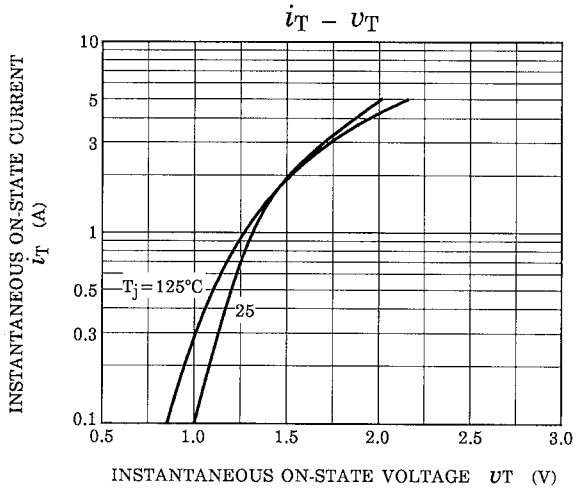


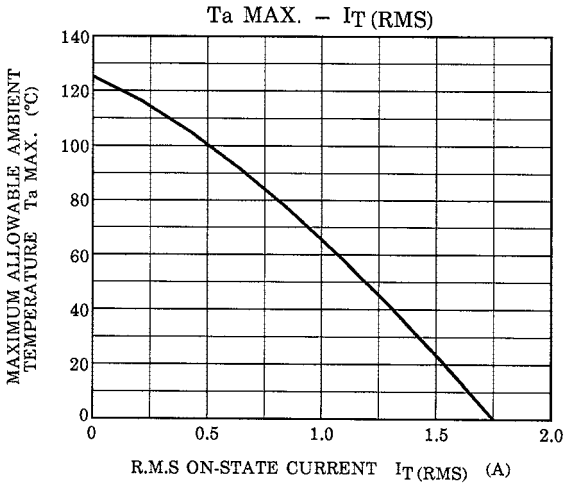
I_H (Tc) / I_H (Tc = 25°C) – Tc (TYPICAL)



TRANSIENT THERMAL IMPEDANCE
(JUNCTION TO AMBINET)







<CONDITION>

- NO HEAT SINK
- LEAD FORMING : LB182
- PRINT BOARD
  (t=1.6mm
  SOLDER LAND : 2mmϕ)

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000707EAA

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